GaAs Flip Chip PIN

**Features**
- Low Series Resistance
- Ultra Low Capacitance
- Millimeter Wave Switching & Cutoff Frequency
- 2 ns Switching Speed
- Can be Driven by a Buffered TTL
- Silicon Nitride Passivation
- Polyimide Scratch Protection
- RoHS* Compliant

**Description**
The MA4GP907 is a Gallium Arsenide (GaAs) flip-chip PIN diode. It is fabricated with MOCVD grown epitaxy using a process and design that optimizes device-to-device uniformity and produces extremely low parasitics. The diode exhibits an exceptionally low RC product (0.1 ps) and a 2 - 3 ns switching speed. The chips are fully passivated with silicon nitride and have an added BCB polymer layer for scratch protection. The BCB protective coating prevents damage to the diode junction and anode air-bridge during handling and assembly.

The ultra low capacitance of the MA4GP907 allows for operation at millimeter wave frequencies for RF switches and phase shifter applications. The diode is designed to be used in pulsed or CW applications, where single digit ns switching speed is required. The low capacitance of this device makes it ideal for use in many microwave multi-throw switch assemblies, where the series capacitance of each "off" port adversely loads the input and affects VSWR.

**Chip Dimensions**

1. Gold Pads 14 µm thick (nominal).
2. Yellow areas indicate ohmic gold mounting pads.

<table>
<thead>
<tr>
<th>Dim.</th>
<th>Inches</th>
<th>Millimeters</th>
</tr>
</thead>
<tbody>
<tr>
<td></td>
<td>Min.</td>
<td>Max.</td>
</tr>
<tr>
<td>A</td>
<td>0.0260</td>
<td>0.0270</td>
</tr>
<tr>
<td>B</td>
<td>0.0135</td>
<td>0.0145</td>
</tr>
<tr>
<td>C</td>
<td>0.0065</td>
<td>0.0075</td>
</tr>
<tr>
<td>D</td>
<td>0.0043</td>
<td>0.0053</td>
</tr>
<tr>
<td>E</td>
<td>0.0068</td>
<td>0.0073</td>
</tr>
<tr>
<td>F</td>
<td>0.0182</td>
<td>0.0192</td>
</tr>
</tbody>
</table>

**Ordering Information**

<table>
<thead>
<tr>
<th>Part Number</th>
<th>Packaging</th>
</tr>
</thead>
<tbody>
<tr>
<td>MA4GP907</td>
<td>Waffle Pack</td>
</tr>
<tr>
<td>MADP-000907-13050P</td>
<td>Pocket Tape</td>
</tr>
</tbody>
</table>
MA4GP907

GaAs Flip Chip PIN

Rev. V10

Electrical Specifications @ $T_A = +25^\circ C$

<table>
<thead>
<tr>
<th>Parameter</th>
<th>Conditions</th>
<th>Units</th>
<th>Min.</th>
<th>Typ.</th>
<th>Max.</th>
</tr>
</thead>
<tbody>
<tr>
<td>Total Capacitance ($C_T$)</td>
<td>-10 V, 1 MHz</td>
<td>pF</td>
<td>0.025</td>
<td>0.030</td>
<td></td>
</tr>
<tr>
<td>Series Resistance ($R_S$)</td>
<td>+10 mA, 1 GHz</td>
<td>Ω</td>
<td>5.2</td>
<td>7.0</td>
<td></td>
</tr>
<tr>
<td>Forward Voltage ($V_F$)</td>
<td>+10 mA</td>
<td>V</td>
<td>1.33</td>
<td>1.45</td>
<td></td>
</tr>
<tr>
<td>Reverse Voltage Current ($I_R$)</td>
<td>$V_R = -50 V$</td>
<td>μA</td>
<td>—</td>
<td>—</td>
<td>10</td>
</tr>
<tr>
<td>Switching Speed ($T_{RISE}/T_{FALL}$)</td>
<td>10 GHz</td>
<td>ns</td>
<td>2</td>
<td>—</td>
<td></td>
</tr>
</tbody>
</table>

3. The max rated reverse voltage ($V_R$) is sourced and the resultant reverse leakage current ($I_R$) is measured to be <10 μA.
4. Switching speed is measured between 10% and 90% or 90% to 10% RF voltage for a single series mounted diode, driver delay is not included.

Absolute Maximum Ratings

<table>
<thead>
<tr>
<th>Parameter</th>
<th>Absolute Maximum</th>
</tr>
</thead>
<tbody>
<tr>
<td>Reverse Voltage</td>
<td>50 V</td>
</tr>
<tr>
<td>CW Incident Power</td>
<td>23 dBm</td>
</tr>
<tr>
<td>RF &amp; DC Dissipated Power</td>
<td>250 mW</td>
</tr>
<tr>
<td>Operating Temperature</td>
<td>-55°C to +125°C</td>
</tr>
<tr>
<td>Storage Temperature</td>
<td>-55°C to +150°C</td>
</tr>
<tr>
<td>Junction Temperature</td>
<td>+175°C</td>
</tr>
<tr>
<td>Mounting Temperature</td>
<td>+280°C for 10 seconds</td>
</tr>
</tbody>
</table>

Circuit Pad Layout

MACOM Technology Solutions Inc. (MACOM) and its affiliates reserve the right to make changes to the product(s) or information contained herein without notice. Visit www.macom.com for additional data sheets and product information.

For further information and support please visit: https://www.macom.com/support

DC-0007455
Typical Performance Curves

**Insertion Loss**

-0.8
-0.6
-0.4
-0.2
0.0

Frequency (GHz) 0 10 20 30 40

**Return Loss**

-40
-30
-20
-10
0

Frequency (GHz) 0 10 20 30 40

**Isolation**

-35
-30
-25
-20
-15
-10
-5
0

Frequency (GHz) 0 10 20 30 40
Cleanliness
This device should be handled in a clean environment. The chip is resistant to solvents and may be cleaned using approved industry standard practices and chemicals.

Static Sensitivity
Gallium Arsenide PIN diodes are ESD sensitive and can be damaged by static electricity. Proper ESD handling techniques should be used in a static-free environment. These devices are rated Class 0 HBM per MIL-STD-883, method 3015.7.

General Handling
The die has a polymer layer which provides scratch protection for the junction area and the anode air bridge. Die can be handled with plastic tweezers or picked and placed with a #27 tip vacuum pencil.

Assembly Requirements
Electrically Conductive Silver Epoxy:
The MA4GP907 is designed to be inserted onto hard or soft substrates with the junction/pad side down. It can be mounted onto a silk-screened circuit using electrically conductive silver epoxy which is approximately 1 - 2 mils thick and cured at approximately 90°C to 150°C per manufacturer’s schedule. For extended cure times, >30 minutes, temperatures must be kept below 200°C.

Solder Die Attached:
The MA4GP907 and the MA4AGP907 (AlGaAs) PIN diode, which both employ the same contact pad metalization scheme (T-W-Au), must use a solder that contains <30% Sn by weight for a reliable die attach to a circuit. An example is a eutectic 80Au/20Sn.

Tin rich solders (>30% Sn by weight) are not recommended as they will scavenge the gold on the contact pads, exposing the tungsten metalization beneath and creating a poor solder connection.

Note:
For an AlGaAs solderable PIN diode version (with Cu-Ni-Au contact pads) where both 60Sn/40Pb (non RoHS) and 96Sn/4Ag (RoHS) type solders can be used, please refer to MACOM’s MADP-00907-14020.
MACOM Technology Solutions Inc. All rights reserved.

Information in this document is provided in connection with MACOM Technology Solutions Inc ("MACOM") products. These materials are provided by MACOM as a service to its customers and may be used for informational purposes only. Except as provided in MACOM's Terms and Conditions of Sale for such products or in any separate agreement related to this document, MACOM assumes no liability whatsoever. MACOM assumes no responsibility for errors or omissions in these materials. MACOM may make changes to specifications and product descriptions at any time, without notice. MACOM makes no commitment to update the information and shall have no responsibility whatsoever for conflicts or incompatibilities arising from future changes to its specifications and product descriptions. No license, express or implied, by estoppels or otherwise, to any intellectual property rights is granted by this document.

THESE MATERIALS ARE PROVIDED "AS IS" WITHOUT WARRANTY OF ANY KIND, EITHER EXPRESS OR IMPLIED, RELATING TO SALE AND/OR USE OF MACOM PRODUCTS INCLUDING LIABILITY OR WARRANTIES RELATING TO FITNESS FOR A PARTICULAR PURPOSE, CONSEQUENTIAL OR INCIDENTAL DAMAGES, MERCHANTABILITY, OR INFRINGEMENT OF ANY PATENT, COPYRIGHT OR OTHER INTELLECTUAL PROPERTY RIGHT. MACOM FURTHER DOES NOT WARRANT THE ACCURACY OR COMPLETENESS OF THE INFORMATION, TEXT, GRAPHICS OR OTHER ITEMS CONTAINED WITHIN THESE MATERIALS. MACOM SHALL NOT BE LIABLE FOR ANY SPECIAL, INDIRECT, INCIDENTAL, OR CONSEQUENTIAL DAMAGES, INCLUDING WITHOUT LIMITATION, LOST REVENUES OR LOST PROFITS, WHICH MAY RESULT FROM THE USE OF THESE MATERIALS.

MACOM products are not intended for use in medical, lifesaving or life sustaining applications. MACOM customers using or selling MACOM products for use in such applications do so at their own risk and agree to fully indemnify MACOM for any damages resulting from such improper use or sale.